

Supplementary Information

Strain-driven magnetostructural kinetics revealed in Heusler alloys

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Supplementary Contents

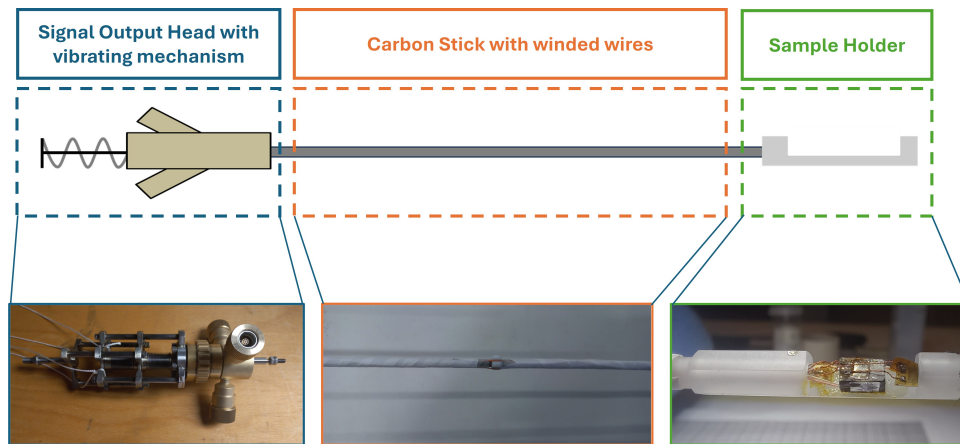
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1 Supplementary Methods

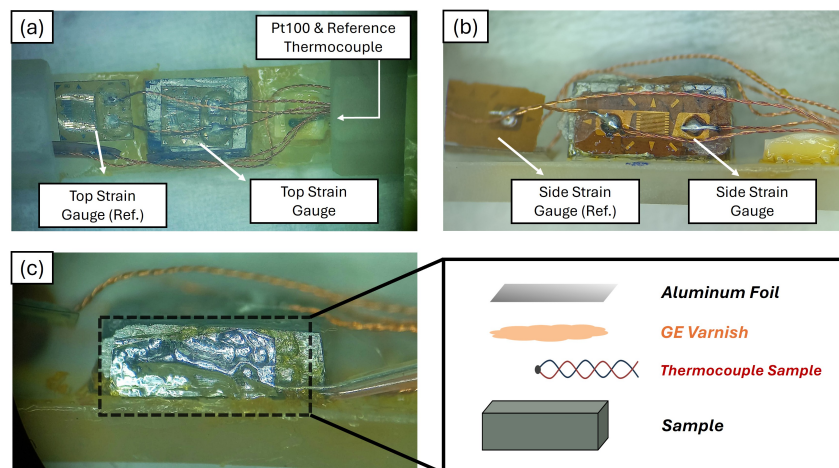
2 Custom-designed simultaneous measuring probe

3 For the simultaneous measurements of magnetization, strain, and sample temperature change,
4 a custom-built probe was designed and build. Figure 1 shows a schematic representation of the
5 whole probe, along with images of each of its constituent sections.



Supplementary Fig. 1: Schematic representation of the custom-designed simultaneous measuring probe, divided into its 3 main sections: (1) Signal output; (2) Carbon Stick, and (3) Sample holder.

6 To accommodate the sample and the sensors used for the simultaneous measurement, a
7 sample holder was designed with a cut-off edge, where the sample was placed. The sample
8 holder is presented in detail in Figures 2 (a), (b) and (c).



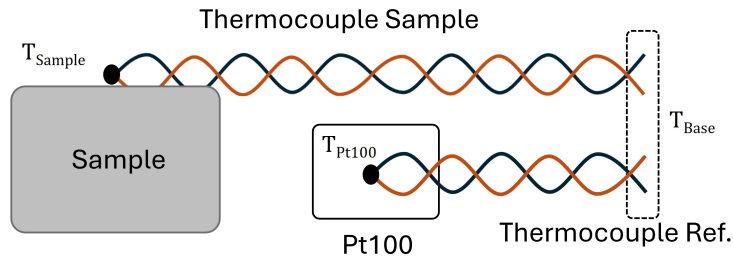
Supplementary Fig. 2: Final assembly of the sample in the sample holder shown in three different perspectives (a) Top view showing the Pt100 and reference thermocouple along with strain gauges (sample and reference) on top of the sample (b) Left side view showing the strain gauges (sample and reference) on the side of the sample (c) Right side of the sample where the thermocouple of the sample is placed. A schematic representation on the right shows the thermocouple assembly process.

9 Strain was measured at two locations on the sample using Vishay Micro-Measurements
 10 linear strain gauges. A strain gauge (model C5K-06-S5145-350) was placed on the top surface
 11 of the sample, which is referred to as the "top strain", seen in Figure 2 (a). On one of the
 12 samples' sides, a strain gauge (model SK-09-031DE-350) was installed, whose measurement
 13 is referred to as the "side strain", seen in Figure 2 (b). To account for external influences on the
 14 strain gauge reading, a "two-strain gauge" configuration was employed. In this configuration,
 15 one strain gauge is glued to the sample, while the other sits free in the sample holder. To further
 16 account for the field-induced signal in the wires, the so-called "parasitic current", a twisted wire
 17 pair was used for all gauges, comprising two 50 μm copper wires. Both gauges were glued with
 18 M-Bond 610 bond from Vishay Micro Measurements.

19 Figure 2 (c) shows the left side of the sample, where a 75 μm type-K thermocouple was
 20 placed. The thermocouple was placed directly on the surface of the sample, before being cov-
 21 ered with GEVarnish and covered with a small aluminum foil, as schematized in Figure 2 (c).

22 Sample Temperature calculation

23 Given the limited amount of space on the sample holder region and other operational constraints
 24 such as having to accommodate wires along the carbon stick and the constant vibration of
 25 the whole probe, the following thermocouple measuring scheme was implemented, as seen in
 26 Figure 3.



Supplementary Fig. 3: Thermocouple wiring scheme used to determine the temperature change of the sample, ΔT_{Sample} . Image not to scale.

27 In this configuration, two 75 μm type-K thermocouples are used. One thermocouple, called
 28 "Thermocouple Sample", is placed on the sample where its tip is considered to be at a tempera-
 29 ture T_{Sample} . The other "Thermocouple Ref." is placed on top of the Pt100 temperature sensor,
 30 and we considered its tip to be at the same temperature as the Pt100 sensor, T_{Pt100} . Both ther-
 31 mocouples are soldered to a section of the soldering pads region, which is considered to be at
 32 an unknown temperature T_{Base} . The voltage reading for each thermocouple will depend on the
 33 temperature on its tip and end section, and will follow the relations described in equations 1
 34 and 2. In these equations, f is a calibration curve for a type-K thermocouple that translates a
 35 temperature into a voltage reading in the thermocouple.

$$V_{Sample} = f(T_{Sample}) - f(T_{Base}) \quad (1)$$

$$V_{Ref} = f(T_{Pt100}) - f(T_{Base}) \quad (2)$$

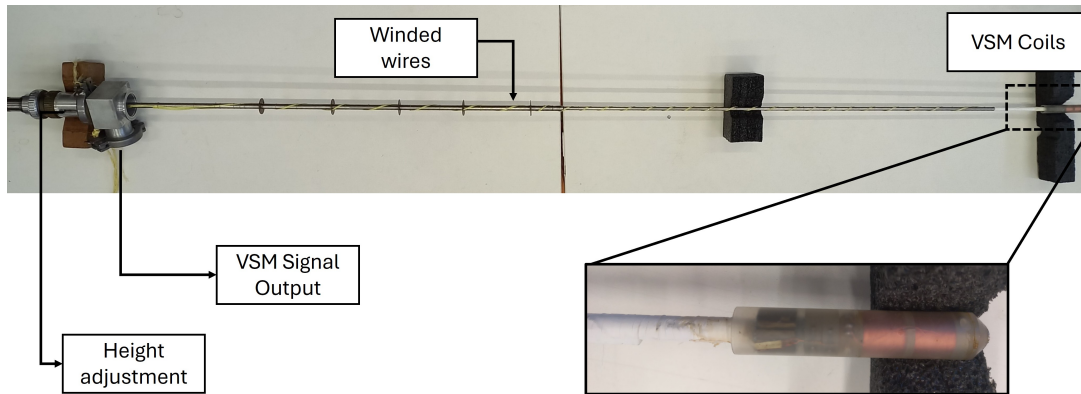
36 Considering that $f(T_{Base})$ is the same for both cases, the sample temperature is then calcu-
 37 lated as shown in equation 3, where f^{-1} is a calibration curve for a type-K thermocouple that
 38 translates the voltage reading in the thermocouples into a temperature.

$$T_{Sample} = f^{-1}(V_{Sample} - V_{Ref} + f(T_{Pt100})) \quad (3)$$

39 It is important to mention that two assumptions were made when using this configuration:
 40 (1) the tip of the "Thermocouple Ref." is at the same temperature as the Pt100; (2) the ends of
 41 both thermocouples are at the same temperature T_{Base} . Although these considerations are rea-
 42 sonable to be made, they can produce a discrepancy in the calculated T_{Sample} value. However,
 43 we do not consider this ΔT_{Sample} value to be an exact temperature of the sample but rather an
 44 estimation of the change in the sample temperature observed in the measurements. Further-
 45 more, given the scope of the manuscript, we are more interested in the time at which a variation
 46 is starting to be detected in the sample temperature and relate this change to the kinetics of the
 47 sample rather than measure a precise variation of this temperature. For this purpose, a specially
 48 designed adiabatic temperature measurement setup should be considered.

49 Full measuring setup

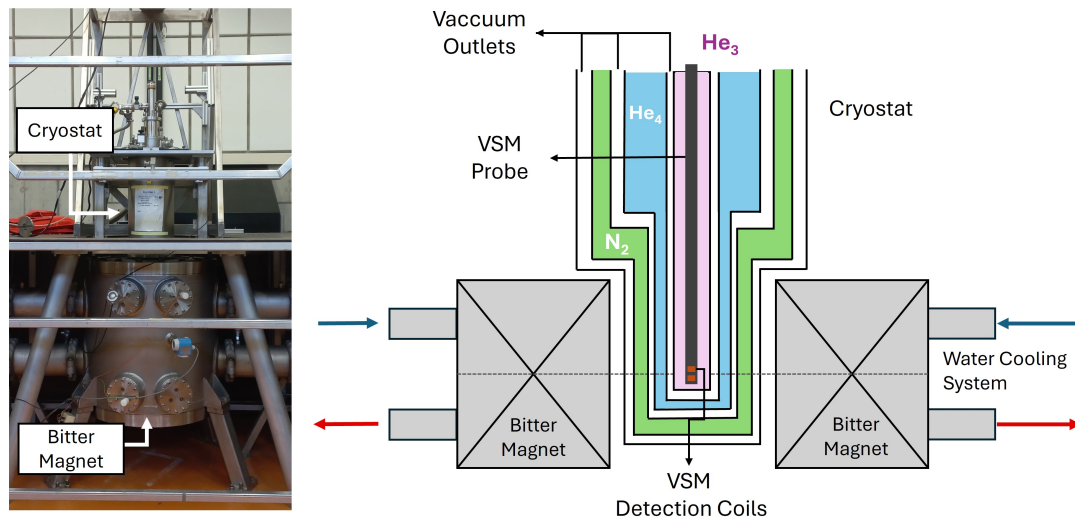
50 To measure magnetization, the custom-designed probe is placed inside a VSM probe used in
 51 the HFML facilities to measure magnetization, as depicted in Figure 4.



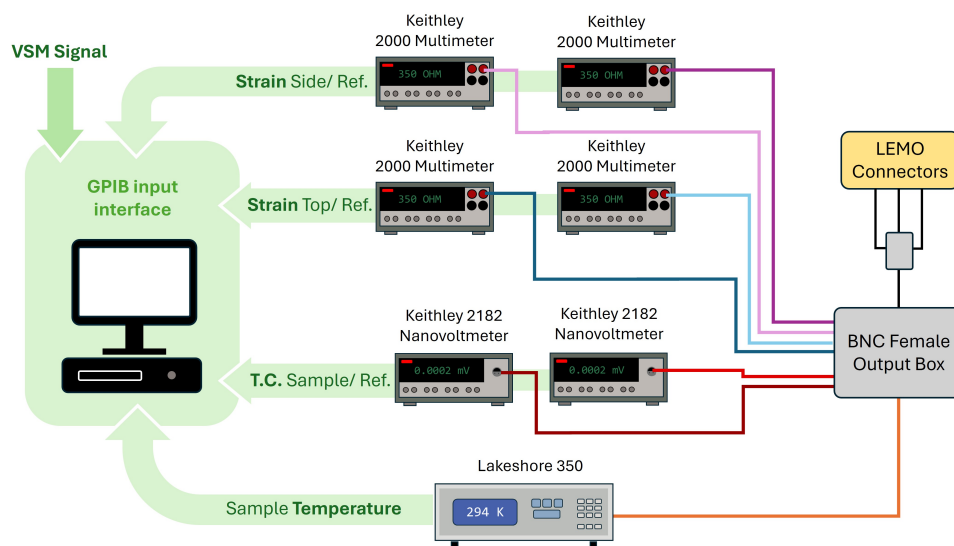
Supplementary Fig. 4: VSM measuring probe commonly used in the High Field Magnetic Laboratory facility to measure magnetization.

52 This probe is composed of VSM detection coils, placed at the end of the VSM probe, whose
 53 signal is then extracted by wires wound along a stick. On the top part of this probe, a LEMO
 54 connection signal output can be found along with a height adjustment screw. This adjustment
 55 is important to place the center of the VSM coils inside the center of the bitter magnet, where
 56 the magnetic field is maximum.

57 Both the custom-designed probe and the VSM probe are placed inside a Bitter magnet,
 58 which can generate magnetic fields up to 30 T with field sweep rates of 10 T/ min. Inside the
 59 bitter magnet, a flow cryostat can be found, which is used to control and set the temperature for
 60 the experiment. Figure 5 shows an image of the bitter magnet cell used, along with a schematic
 61 representation of the flow cryostat.



Supplementary Fig. 5: (left) Image of the bitter magnet cell used with a flow cryostat (right) Schematic representation of the flow cryostat used in the experiment.



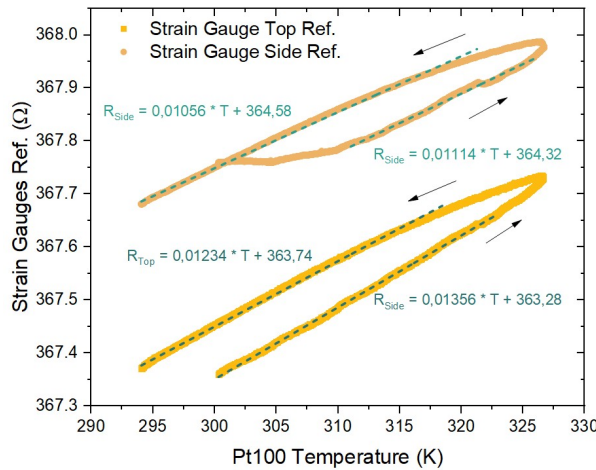
Supplementary Fig. 6: Scheme depicting the wiring configuration used to extract the signals coming from the sensors located in the sample holder. All signals are collected in a GPIB interface and recorded simultaneously in a Labview program.

62 Figure 6 schematizes the full data acquisition of the sensors placed in the sample holder
 63 and the VSM signal. Once both the custom-design probe and VSM probe are placed inside the
 64 magnet, the LEMO connectors' signal is extracted and brought to an output connection box,

65 composed of 24 BNC female outputs. Each of these BNC outputs will correspond to a given
 66 signal coming from the sensors in the sample holder. These outputs are then connected to a
 67 given device to proceed with the data reading and collection. For strain gauges, all four sensors
 68 are connected to a Keithley 2000 Multimeter. The two thermocouples used are connected to a
 69 Keithley 2182 nanovoltmeter. Finally, the Pt100 sensor is plugged into a Lakeshore 350, where
 70 the calibration curve from resistance (Ω) to temperature (K) was uploaded. All of these signals
 71 are then extracted from a GPIB connection and plugged to a computer, where they are collected
 72 and saved in a Labview program at an acquisition rate of around 400 ms.

73 Strain gauge data analysis

74 For each set of measurements, special care with the strain gauge data analysis was taken into ac-
 75 count. This analysis primarily consists of detecting external contributions such as temperature
 76 variations on the detected strain gauge signal. Before starting the kinetic protocols measure-
 77 ments, a temperature dependence was done, and the variation of the reference strain gauges
 78 was recorded, as shown in Figure 7.

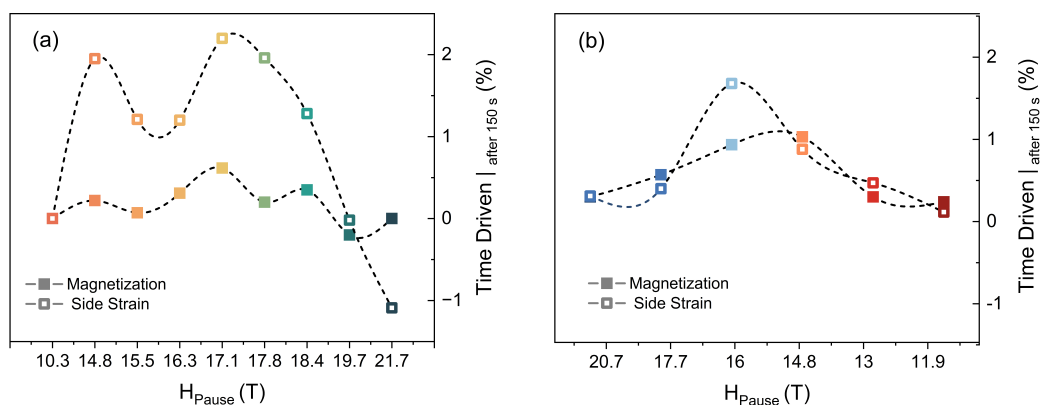


Supplementary Fig. 7: Top and side strain gauge measured values as a function of the temperature of the Pt100 sensor for a temperature range between 294 K up to 326 K. Arrows indicate the heating and cooling process. Linear fits were performed on each cooling/heating section of the data, whose result is presented next to the fit.

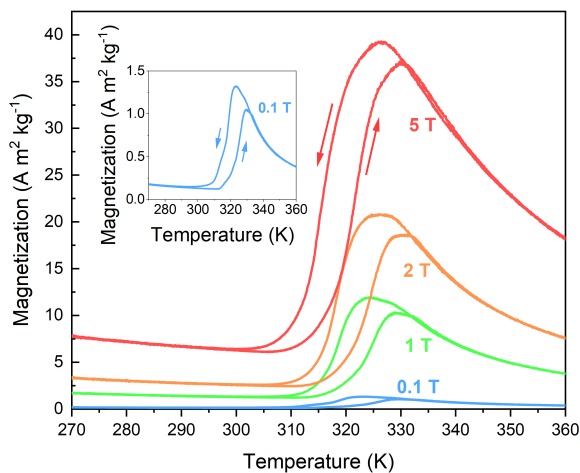
79 Throughout the entire set of experiments presented in the manuscript, the temperature of
 80 the experiment was kept rather constant, having obtained deviations from 0.2 K to 0.6 K. From
 81 the data shown in Figure 7, we estimated the strain variation associated with the thermal lag
 82 detected by the Pt100 sensor. The corrected strain signal was then converted to $\Delta L/L_0$ (%)
 83 using Equation 4.

$$\left(\frac{R - R_0}{R} \right) * \frac{1}{G.F.} * 100 = \Delta L/L_0(\%) \quad (4)$$

84 Here, R (Ω) is the corrected resistance, R_0 (Ω) the initial resistance, and $G.F.$ (gauge
 85 factor), a constant specific to each strain gauge model.



Supplementary Fig. 8: Evolution of the magnetization and side strain fractions during the simultaneous measurements for (a) forward transition and (b) reverse transition from $t = 150$ s up to $t = 300$ s after the field is halted.



Supplementary Fig. 9: Temperature dependence of magnetization for different applied magnetic fields. The inset shows the magnetization curve measured at 0.1 T.